

TECHNICAL DATA

NPN HIGH POWER SILICON TRANSISTOR

Qualified per MIL-PRF-19500/384

Devices Qualified Level

2N3584 2N3585

JAN JANTX JANTXV

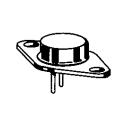
MAXIMUM RATINGS

Ratings	Symbol	2N3584	2N3585	Units
Collector-Emitter Voltage	V_{CEO}	250	300	Vdc
Collector-Base Voltage	V_{CBO}	375	500	Vdc
Collector-Base Voltage	V_{CER}	300	400	Vdc
Emitter-Base Voltage	$V_{\rm EBO}$	6.0		Vdc
Base Current	I_B	1.0		Adc
Collector Current	I_{C}	2.0		Adc
Total Power Dissipation @ $T_A = +25^0 C^{(1)}$	P_{T}	2.	5	W
		35	5	W
Operating & Storage Junction Temperature Range	T _J , T _{stg}	-65 to	+200	°C

THERMAL CHARACTERISTICS

Characteristics	Symbol	Max.	Unit
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	5.0	⁰ C/W

- 1) Derate linearly @ $14.85 \text{ mW/}^{\circ}\text{C}$ for $T_A > +25^{\circ}\text{C}$
- 2) Derate linearly @ 200 mW/ $^{\circ}$ C for $T_C > +25^{\circ}$ C



TO-66* (TO-213AA)

*See Appendix A for Package Outline

ELECTRICAL CHARACTERISTICS (T_C = 25⁰C unless otherwise noted)

Characteristic	cs	Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage					
$I_C = 10 \text{ mAdc}$	2N3584	$V_{(BR)CEO}$	250		Vdc
	2N3585		300		
Collector-Base Breakdown Voltage					
$I_C = 15 \text{ mAdc}$	2N3584	$V_{(BR)CER}$	375		Vdc
	2N3585		500		
Collector-Emitter Cutoff Current					
$V_{CE} = 150 \text{ Vdc}$		I_{CEO}		5.0	mAdc
Collector-Emitter Cutoff Current					
$V_{CE} = 300 \text{ Vdc}, V_{BE} = 1.5 \text{ Vdc}$	2N3584	I_{CEX}		1.0	mAdc
$V_{CE} = 400 \text{ Vdc}, V_{BE} = 1.5 \text{ Vdc}$	2N3585			1.0	
Emitter-Base Cutoff Current					
$V_{EB} = 6.0 \text{ Vdc}$		I_{EBO}		0.5	mAdc

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ELECTRICAL CHARACTERISTICS (con't)

Characteristics	Symbol	Min.	Max.	Unit
ON CHARACTERISTICS (3)				
Forward-Current Transfer Ratio				
$I_C = 1.0 \text{ Adc}, V_{CE} = 10 \text{ Vdc}$	$h_{ m FE}$	25	100	
$I_C = 100 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}$		40		
Collector-Emitter Saturation Voltage				
$I_C = 1.0 \text{ Adc}, I_B = 0.125 \text{ Adc}$	V _{CE(sat)}		0.75	Vdc
Base-Emitter Saturation Voltage				
$I_C = 1.0 \text{ Adc}, I_B = 0.1 \text{ Adc}$	V _{BE(sat)}		1.4	Vdc
DYNAMIC CHARACTERISTICS				
Magnitude of Common Emitter Small-Signal Short-Circuit				
Forward Current Transfer Ratio				
$I_C = 200 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 5.0 \text{ MHz}$	$ h_{\rm fe} $	3.0	15	
Small-Signal Short-Circuit Forward Current Transfer Ratio				
$I_C = 1.0 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}$	h_{fe}	25	200	
Output Capacitance				
$V_{CB} = 10 \text{ Vdc}, I_E = 0, 100 \text{ kHz} \le f \le 1.0 \text{ MHz}$	C_{obo}		120	pF
SWITCHING CHARACTERISTICS				
Turn-On Time				
$V_{CC} = 30 \text{ Vdc}$; $I_C = 1.0 \text{ Adc}$; $I_B = 100 \text{ mAdc}$; $R_C = 29 \Omega$	^t on		3.0	μs
Turn-Off Time				
$V_{CC} = 30 \text{ Vdc}; I_C = 1.0 \text{ Adc}; I_B = -I_B = 100 \text{ mAdc}; R_C = 29 \Omega$	^t off		7.0	μs

SAFE OPERATING AREA

DC Tests

 $T_C = +25^{\circ}C$, 1 Cycle, t = 1.0 s

Test 1

 $V_{CE} = 17.5 \text{ Vdc}, I_{C} = 2.0 \text{ Adc}$

Test 2

 $V_{CE} = 100 \text{ Vdc}, I_C = 350 \text{ mAdc}$

Test 3

 $V_{CE} = 250 \text{ Vdc}, I_{C} = 37 \text{ mAdc}$ 2N3584 $V_{CE} = 300 \text{ Vdc}, I_{C} = 17 \text{ mAdc}$ 2N3585

(3) Pulse Test: Pulse Width = 300μ s, Duty Cycle $\leq 2.0\%$.

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